Application Note No. 114

Investigation of BFR740L3 Ultra Low Noise SiGe:C Transistor as 1.7 - 2.3 GHz "iBURST" Low Noise Amplifier

RF & Protection Devices



Edition 2007-08-22

Published by Infineon Technologies AG 81726 München, Germany © Infineon Technologies AG 2009. All Rights Reserved.

LEGAL DISCLAIMER

THE INFORMATION GIVEN IN THIS APPLICATION NOTE IS GIVEN AS A HINT FOR THE IMPLEMENTATION OF THE INFINEON TECHNOLOGIES COMPONENT ONLY AND SHALL NOT BE REGARDED AS ANY DESCRIPTION OR WARRANTY OF A CERTAIN FUNCTIONALITY, CONDITION OR QUALITY OF THE INFINEON TECHNOLOGIES COMPONENT. THE RECIPIENT OF THIS APPLICATION NOTE MUST VERIFY ANY FUNCTION DESCRIBED HEREIN IN THE REAL APPLICATION. INFINEON TECHNOLOGIES HEREBY DISCLAIMS ANY AND ALL WARRANTIES AND LIABILITIES OF ANY KIND (INCLUDING WITHOUT LIMITATION WARRANTIES OF NON-INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHTS OF ANY THIRD PARTY) WITH RESPECT TO ANY AND ALL INFORMATION GIVEN IN THIS APPLICATION NOTE.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.



<u> </u>	North and the Mark Mark Add							
Applica	tion Note No. 114							
Revisio	n History: 2007-08-22, Rev. 1.2							
Previou	s Version: 2005-07-22, Rev. 1.1							
Page	Subjects (major changes since last revision)							
All	Small changes in figure descriptions							

Application Note 3 Rev. 1.2, 2007-08-22



1 Investigation of BFR740L3 Ultra Low Noise SiGe:C Transistor as 1.7 - 2.3 GHz "iBURST" Low Noise Amplifier

Applications

General purpose LNA for iBURST system

Overview

- Infineon BFR740L3 Ultra Low Noise SiGe:C Transistor in reduced-height TSLP-3-8 package is shown in a low-cost, low-parts count, broadband resistive feedback low noise amplifier.
- LNA is characterized for the 1.7 2.3 GHz frequency range.
- Transistor package size is 1 x 0.6 x 0.39 mm (leadless, RoHS compliant package).
- Note that "0201" size passive components are used.
- Current consumption is 12.9 mA at 3.0 volts.
- Amplifier is unconditionally stable (K>1) over 5 MHz 8 GHz frequency range.

Summary of Results

Table 1 Summary of Results (T = 25 °C)

Frequency MHz	dB[s11] ²	dB[s21] ²	dB[12] ²	dB[22] ²	NF *	IIP ₃ dBm	OIP ₃ dBm	IP _{1dB} dBm	OP _{1dB} dBm
1700	10.4	18.3	23.4	10.7	1.0				
2000	11.8	17.3	22.4	10.9	1.0	+0.3	+17.6	-10.0	+6.3
2300	13.0	16.2	21.5	10.6	1.0				

^{*} Note that PCB loss is not extracted. If PCB loss were extracted, NF would be 0.1 to 0.2 dB lower.

Cross Sectional Diagram of PC Board

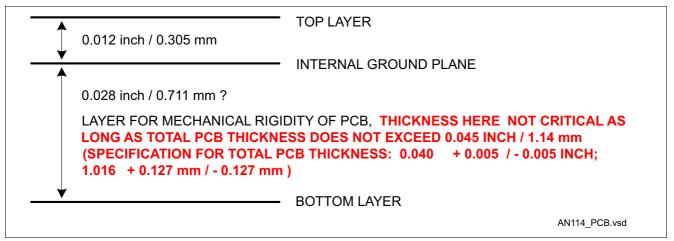


Figure 1 PCB - Cross Sectional Diagram

Application Note 4 Rev. 1.2, 2007-08-22



Schematic Diagram

Note: "0201" case size passives are used

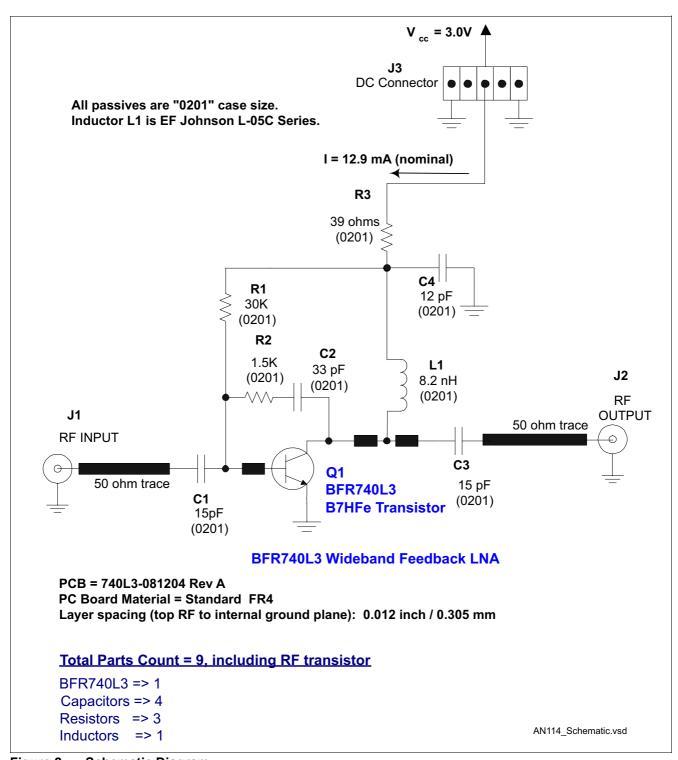


Figure 2 Schematic Diagram

Application Note 5 Rev. 1.2, 2007-08-22



Details on TSLP-3-8 Leadless Package, dimensions in millimeters (mm)

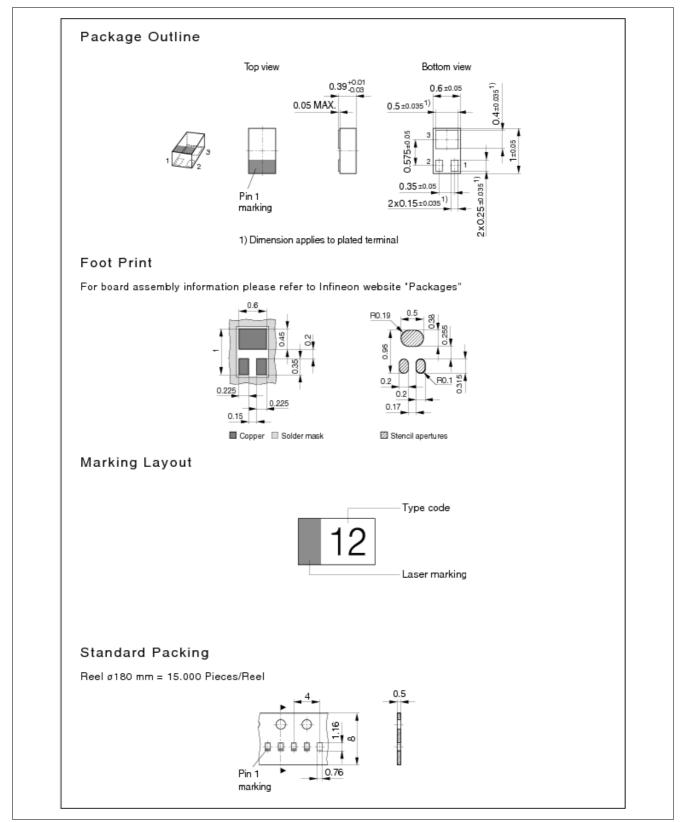


Figure 3 Details on TSLP-2-8 Leadless Package

Application Note 6 Rev. 1.2, 2007-08-22



Noise Figure, Plot, 1.4 to 2.6 GHz. Center of Plot (x-axis) is 2.0 GHz.

Rohde & Schwarz FSEK3

22 Jul 2005

AN114_plot_nf.vsd

Noise Figure

EUT Name: BFR740L3 1.7 - 2.3 GHz iBURST LNA,

Manufacturer: Infineon Technologies AG
Operating Conditions: V=3.0V, I=12.9mA, T = 25 C
Operator Name: Gerard Wevers

Operator Name: Gerard Wevers
Test Specification: LWR SD00083 LNA P
Comment: On PCB 740L3-081204 Rev A

22 July 2005

<u>Analyzer</u>

 RF Att:
 0.00 dB
 RBW:
 1 MHz
 Range:
 40.00 dB

 Ref LvI:
 -41.00 dBm
 VBW:
 100 Hz
 Ref LvI auto:
 ON

Measurement

2nd stage corr: ON Mode: Direct ENR: HP346A.ENR

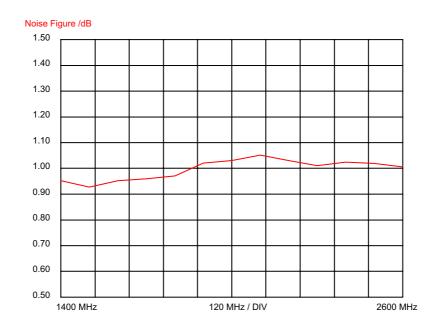


Figure 4 Noise Figure

Application Note 7 Rev. 1.2, 2007-08-22



Noise Figure, Tabular Data

From Rhode & Schwarz FSEK3 + FSEM30 + System PreAmp

Table 2 Noise Figure

Frequency	Noise Figure	
1400 MHz	0.95 dB	
1504 MHz	0.93 dB	
1600 MHz	0.95 dB	
1700 MHz	0.96 dB	
1800 MHz	0.97 dB	
1904 MHz	1.02 dB	
2000 MHz	1.03 dB	
2100 MHz	1.05 dB	
2200 MHz	1.03 dB	
2300 MHz	1.01 dB	
2400 MHz	1.02 dB	
2500 MHz	1.02 dB	
2600 MHz	1.01 dB	

Application Note 8 Rev. 1.2, 2007-08-22



Scanned Image of PC Board

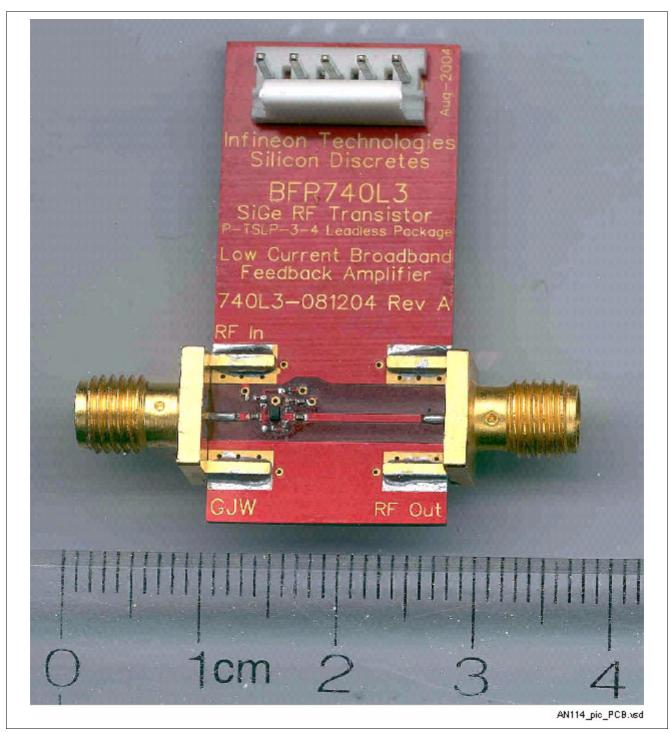


Figure 5 Image of PC Board



Scanned Image of PC Board, Close-In Shot

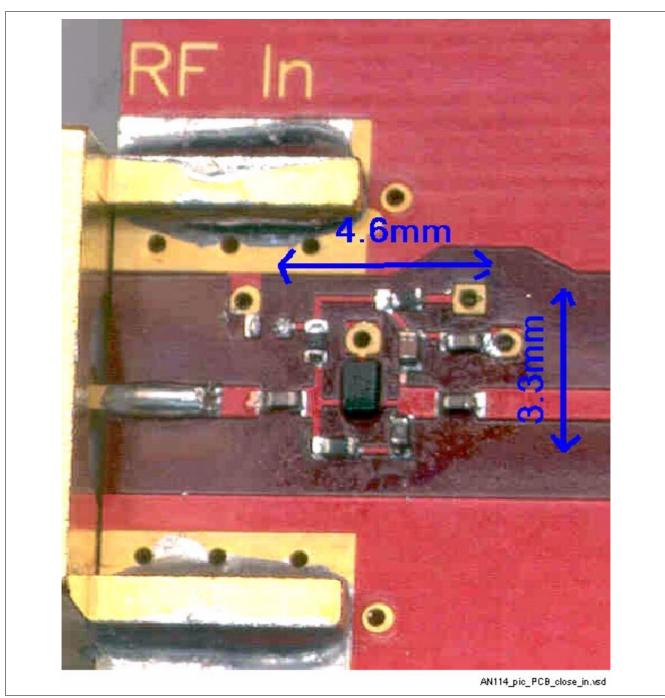


Figure 6 Image of PC Board, Close-In Shot

Application Note 10 Rev. 1.2, 2007-08-22



Gain Compression at 3.5 GHz

Amplifier is checked for 1 dB compression point at $V_{\rm CC}$ = 3.0 V, $I_{\rm C}$ = 12.9 mA (with $V_{\rm CE}$ = 2.5 V). An Agilent power meter was used to ensure accurate power levels are measured (as opposed to using Vector Network Analyzer in "Power Sweep" mode).

Output $P_{1dB} \cong +6.3 \text{ dBm}$; Input $P_{1dB} = +6.3 \text{ dBm}$ - (Gain - 1 dB) = +6.3 dBm -16.3 dB = -10.0 dBm

Table 3 Gain Compression

P _{OUT} , dBm	Gain, dB
-7.0	17.3
-6.0	17.3
-5.0	17.3
-4.0	17.3
-3.0	17.3
-2.0	17.3
-1.0	17.3
0.0	17.3
+1.0	17.2
+2.0	17.2
+3.0	17.1
+4.0	17.0
+5.0	16.9
+6.0	16.5
+7.0	15.8

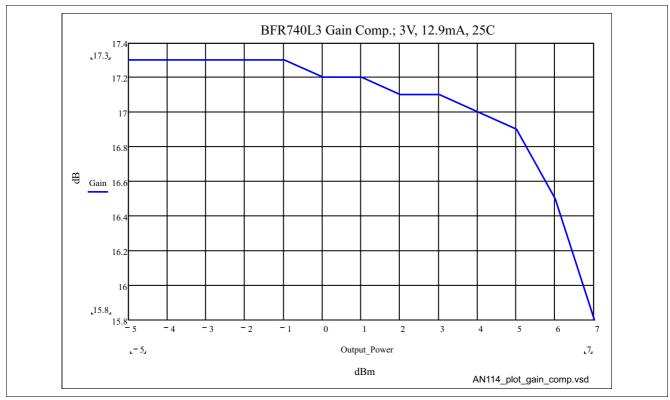


Figure 7 Gain Compression at 3.5 GHz

Application Note 11 Rev. 1.2, 2007-08-22



Stability

Rohde and Schwarz ZVC Network Analyzer calculates and plots Stability Factor "K" in real time, from 5 MHz to 8 GHz.

Note K>1 from 5 MHz to 8 GHz. Amplifier is Unconditionally Stable over 5 MHz - 8 GHz frequency range

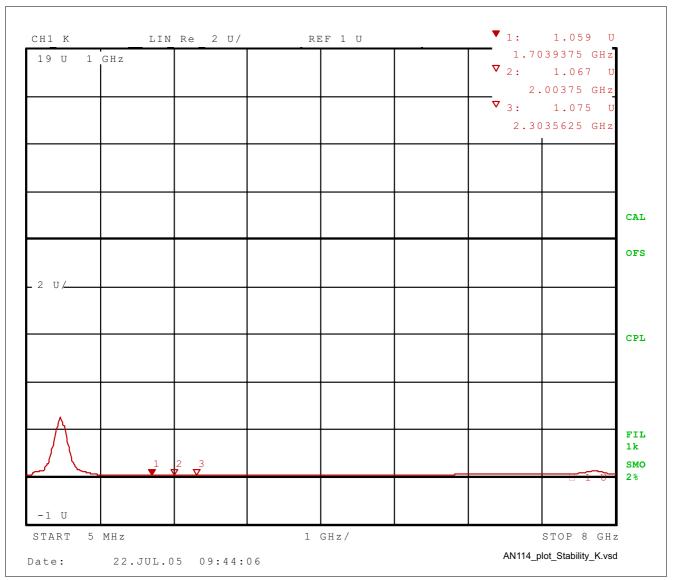


Figure 8 Plot of K(f)

Application Note 12 Rev. 1.2, 2007-08-22



Note: All plots are from Rohde and Schwart ZVC Network Analyzer, T = 25 °C, Source Power \cong -30 dBm, $V_{\rm CC}$ = 3.0 V, I = 12.9 mA

Input Return Loss, Log Mag

5 MHz to 8 GHz Sweep

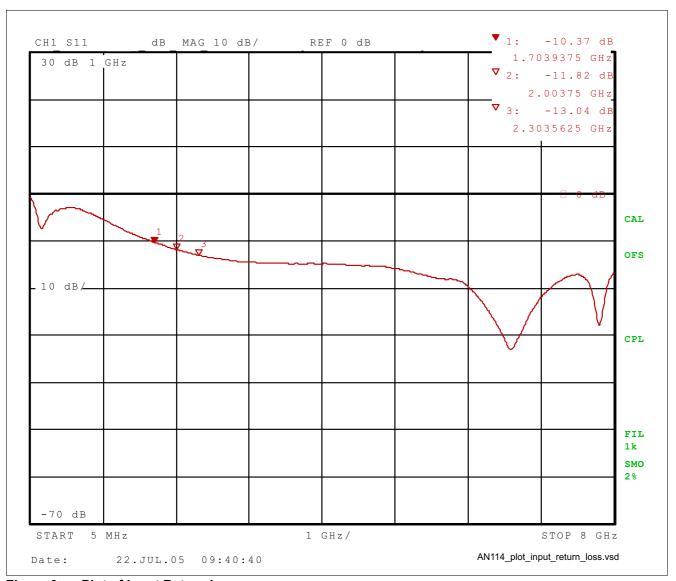


Figure 9 Plot of Input Return Loss

Application Note 13 Rev. 1.2, 2007-08-22



Input Return Loss, Smith Chart

Reference Plane = Input SMA Connector on PC Board 5 MHz to 8 GHz Sweep

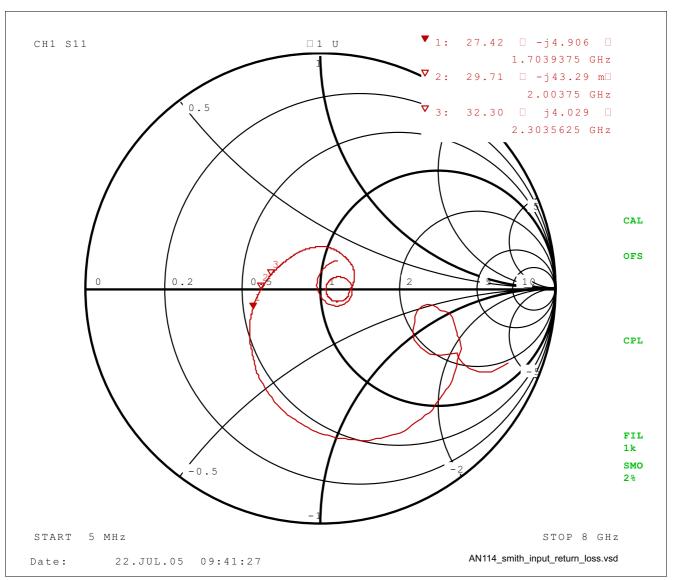


Figure 10 Smith Chart of Input Return Loss

Application Note 14 Rev. 1.2, 2007-08-22



Forward Gain, Wide Sweep

5 MHz to 8 GHz Sweep

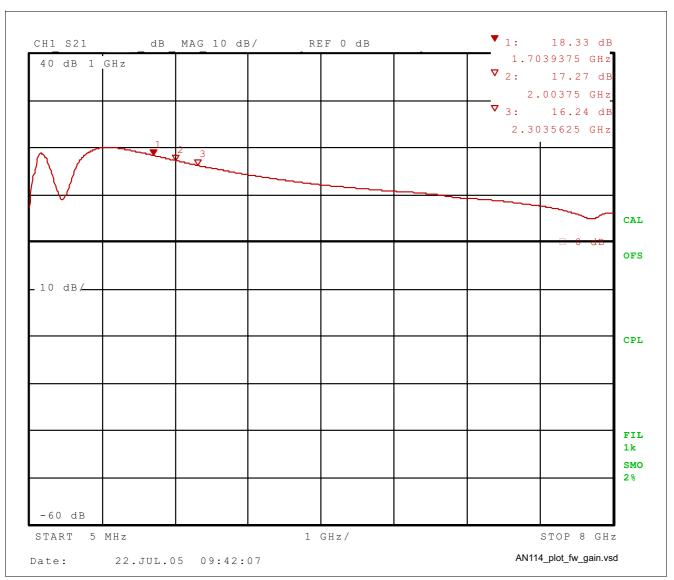


Figure 11 Plot of Forward Gain

Application Note 15 Rev. 1.2, 2007-08-22



Reverse Isolation

5 MHz to 8 GHz

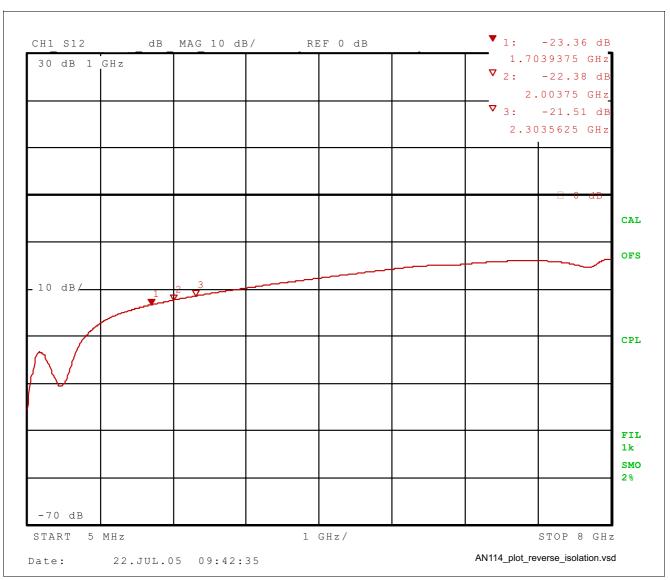


Figure 12 Plot of Reverse Isolation

Application Note 16 Rev. 1.2, 2007-08-22



Output Return Loss, Log Mag

5 MHz to 8 GHz

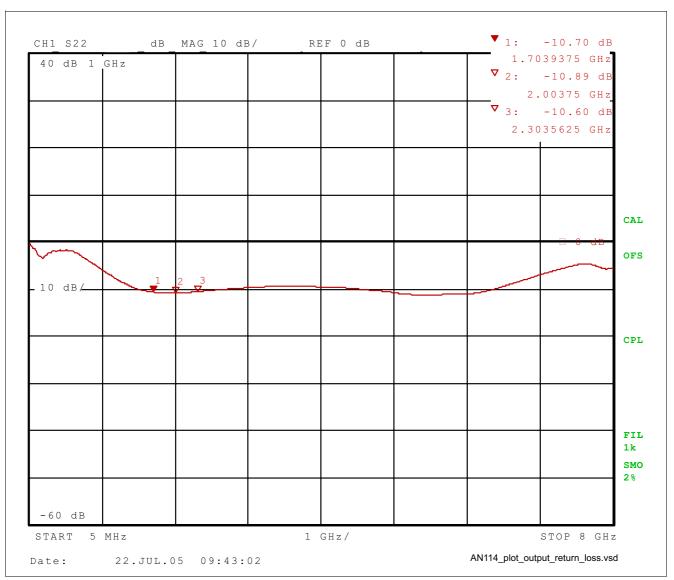


Figure 13 Plot of Output Return Loss

Application Note 17 Rev. 1.2, 2007-08-22



Output Return Loss, Smith Chart

Reference Plane = Output SMA Connector on PC Board 5 MHz to 8 GHz Sweep

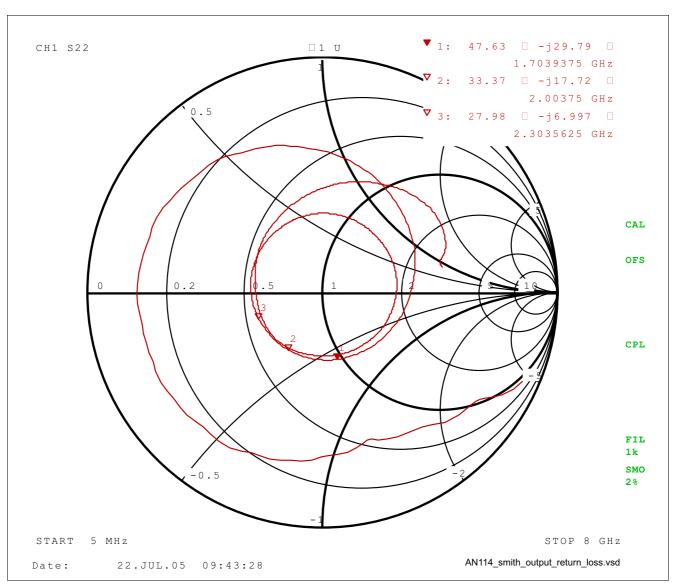


Figure 14 Smith Chart of Output Return Loss

Application Note 18 Rev. 1.2, 2007-08-22



Two-Tone Test, 2.0 GHz

Input Stimulus for Amplifier Two-Tone Test f_1 = 2000 MHz, f_2 = 2001 MHz, -23 dBm each tone Input IP_3 = -23 + (46.5 / 2) = +0.3 dBm Output IP_3 = +0.3 dBm + 17.3 dB gain = +17.6 dBm

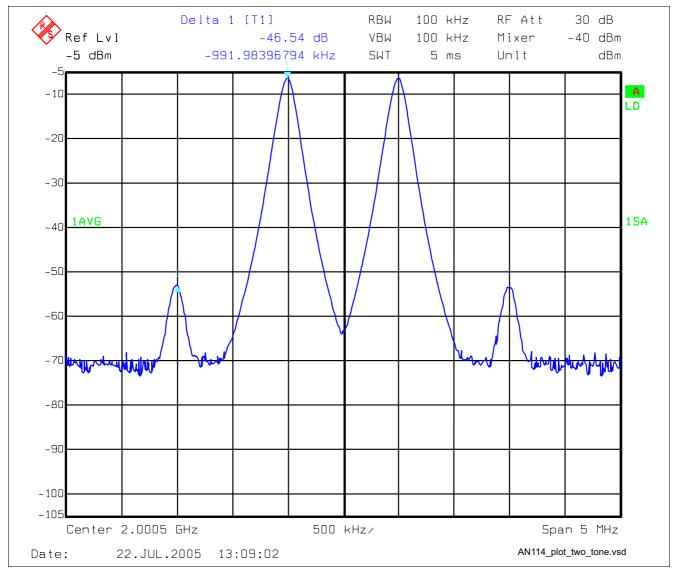


Figure 15 Tow-Tone Test

Application Note 19 Rev. 1.2, 2007-08-22